Power MOSFET 30 V, 37 A, Single N–Channel, DPAK/IPAK

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- Optimized Gate Charge to Minimize Switching Losses
- These are Pb–Free Devices

Applications

- CPU Power Delivery
- DC–DC Converters

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parar	neter		Symbol	Value	Unit
Drain-to-Source Volta	V _{DSS}	30	V		
Gate-to-Source Volta	V _{GS}	±20	V		
Continuous Drain		$T_A = 25^{\circ}C$	۱ _D	11.2	A
Current (R _{θJA}) (Note 1)		T _A = 100°C		7.9	
Power Dissipation $(R_{\theta JA})$ (Note 1)		T _A = 25°C	P _D	2.6	W
Continuous Drain		T _A = 25°C	۱ _D	8.2	А
Current (R _{θJA}) (Note 2)	Steady	$T_A = 100^{\circ}C$		5.8	
Power Dissipation $(R_{\theta JA})$ (Note 2)	State	$T_A = 25^{\circ}C$	PD	1.37	W
Continuous Drain		$T_C = 25^{\circ}C$	I _D	37	А
Current (R _{θJC}) (Note 1)		$T_C = 100^{\circ}C$		26	
Power Dissipation $(R_{\theta JC})$ (Note 1)		T _C = 25°C	P _D	27.3	W
Pulsed Drain Current	t _p =10μs	T _A = 25°C	I _{DM}	152	А
Current Limited by Pac	kage	T _A = 25°C	I _{DmaxPkg}	60	А
Operating Junction and	I Storage 1	Femperature	T _J , T _{stg}	-55 to 175	°C
Source Current (Body I	۱ _S	23	А		
Drain to Source dV/dt	dV/dt	7.0	V/ns		
Single Pulse Drain-to- Energy ($T_J = 25^{\circ}C$, V_{DI} L = 0.1 mH, $I_{L(pk)} = 22$.	E _{AS}	25.3	mJ		
		Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface-mounted on FR4 board using 1 in sq pad size, 1 oz Cu.

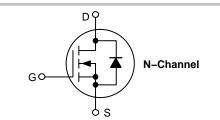
2. Surface-mounted on FR4 board using the minimum recommended pad size.

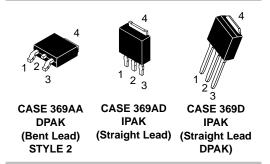


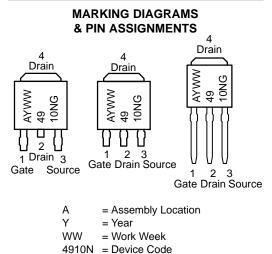
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V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX
30 V	9.0 mΩ @ 10 V	37 A
30 V	13 mΩ @ 4.5 V	57 A







ORDERING INFORMATION

= Pb-Free Package

G

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain)	$R_{ extsf{ heta}JC}$	5.5	°C/W
Junction-to-Tab (Drain)	$R_{\theta JC-TAB}$	4.3	
Junction-to-Ambient - Steady State (Note 3)	$R_{\theta JA}$	58.5	
Junction-to-Ambient - Steady State (Note 4)	$R_{ hetaJA}$	109.7	

3. Surface-mounted on FR4 board using 1 in sq pad size, 1 oz Cu.

4. Surface-mounted on FR4 board using the minimum recommended pad size.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							-
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 V, I_D$	= 250 μA	30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				15		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	$T_J = 25^{\circ}C$			1.0	μΑ
		$V_{DS} = 24 V$	$T_J = 125^{\circ}C$			10	
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 V, V_{GS}$	$_{3} = \pm 20 \text{ V}$			±100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= 250 μA	1.0	1.6	2.2	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				4.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V	I _D = 30 A		7.5	9.0	mΩ
			I _D = 15 A		7.5		1

10.6

10.6

40

13

S

$V_{GS} = 4.5 \text{ V} \qquad I_D = 30 \text{ A}$ $I_D = 15 \text{ A}$ Forward Transconductance gFS $V_{DS} = 1.5 \text{ V}, I_D = 30 \text{ A}$

CHARGES AND CAPACITANCES

Input Capacitance	C _{iss}		1203	pF
Output Capacitance	C _{oss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 15 V	460	
Reverse Transfer Capacitance	C _{rss}		12.5	
Total Gate Charge	Q _{G(TOT)}		6.8	nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = 4.5 V, V _{DS} = 15 V, I _D = 30 A	1.95	
Gate-to-Source Charge	Q _{GS}	I _D = 30 A	3.9	
Gate-to-Drain Charge	Q _{GD}		1.1	
Total Gate Charge	Q _{G(TOT)}	$V_{GS} = 10 \text{ V}, V_{DS} = 15 \text{ V},$ $I_D = 30 \text{ A}$	15.4	nC

SWITCHING CHARACTERISTICS (Note 6)

Turn–On Delay Time	t _{d(on)}		11.6	ns
Rise Time	t _r	V _{GS} = 4.5 V, V _{DS} = 15 V,	21.8	
Turn-Off Delay Time	t _{d(off)}	I_D = 15 A, R _G = 3.0 Ω	16.5	
Fall Time	t _f		4.2	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%.

6. Switching characteristics are independent of operating junction temperatures.

7. Assume terminal length of 110 mils.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Test Cond	Test Condition		Тур	Max	Unit
Turn-On Delay Time	t _{d(on)}				7.3		ns
Rise Time	tr	V _{GS} = 10 V, V _D	V_{GS} = 10 V, V_{DS} = 15 V, I _D = 15 A, R _G = 3.0 Ω		19.5		
Turn-Off Delay Time	t _{d(off)}	I _D = 15 A, R _G			20.2		
Fall Time	t _f			2.0			
Forward Diode Voltage	CTERISTICS V _{SD}	V _{GS} = 0 V,	T,₁ = 25°C		0.91	1.1	V
0		$I_{\rm S} = 30 \rm{A}$	T _J = 125°C		0.82		
Reverse Recovery Time	t _{RR}				27		ns
Charge Time	ta	V_{GS} = 0 V, dls/dt= 100 A/µs, I _S = 30 A			14		
Discharge Time	tb				13		1
Reverse Recovery Time	Q _{RR}	1			17		nC

PACKAGE PARASITIC VALUES

Source Inductance (Note 7)	L _S		2.99		nH
Drain Inductance, DPAK	LD		0.0164		
Drain Inductance, IPAK (Note 7)	L _D	$T_A = 25^{\circ}C$	1.88		
Gate Inductance (Note 7)	L _G		4.9		
Gate Resistance	R _G		1.0	2.0	Ω

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2%. 6. Switching characteristics are independent of operating junction temperatures.

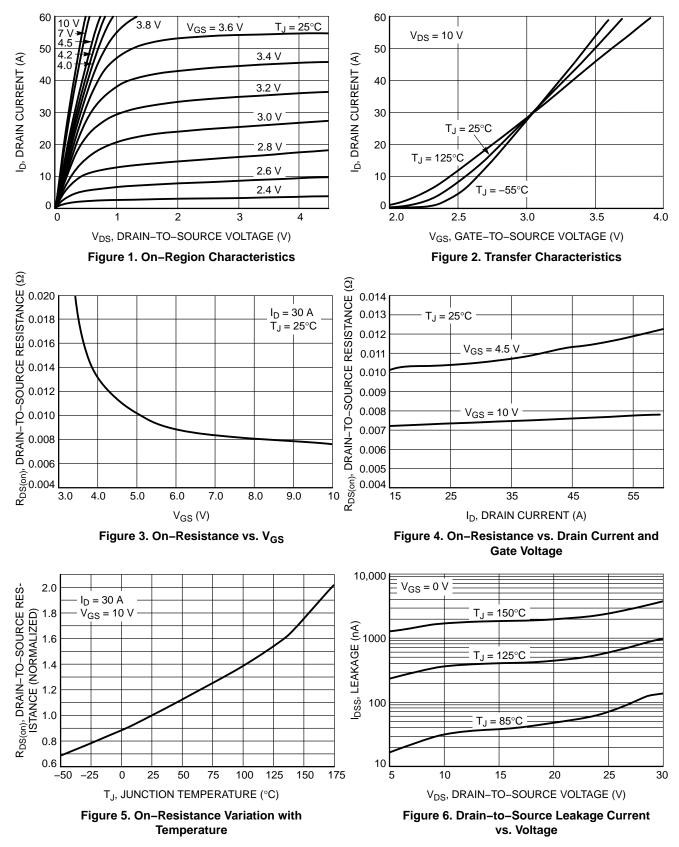
7. Assume terminal length of 110 mils.

ORDERING INFORMATION

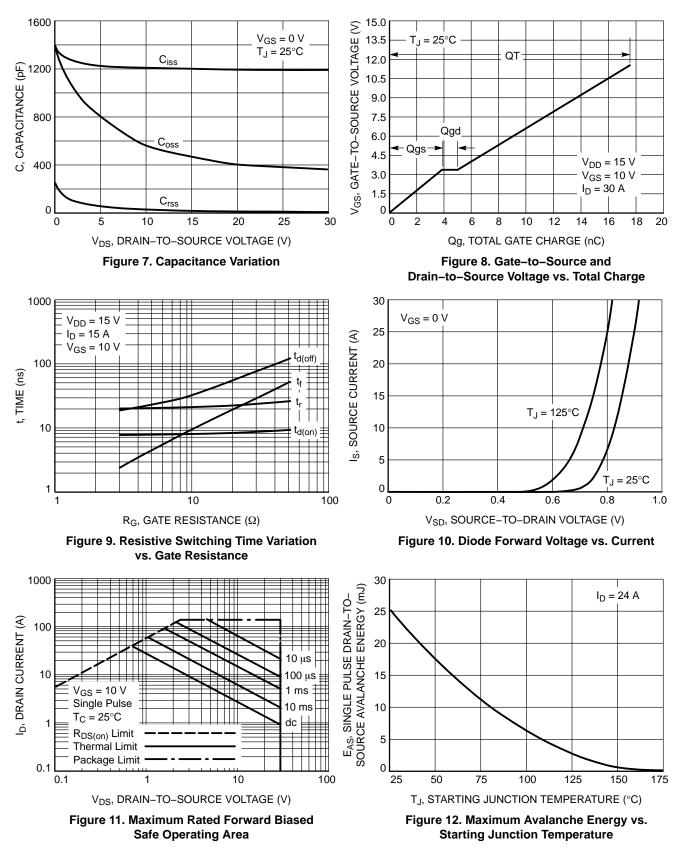
Order Number	Package	Shipping [†]
NTD4910NT4G	DPAK (Pb–Free)	2500 / Tape & Reel
NTD4910N-1G	IPAK (Pb-Free)	75 Units / Rail
NTD4910N-35G	IPAK Trimmed Lead (Pb-Free)	75 Units / Rail

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

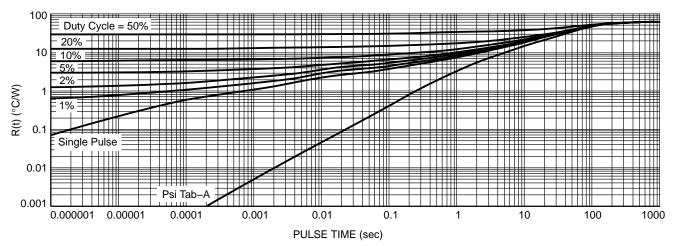




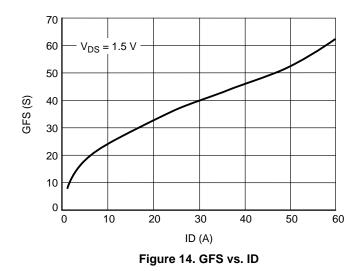




TYPICAL CHARACTERISTICS









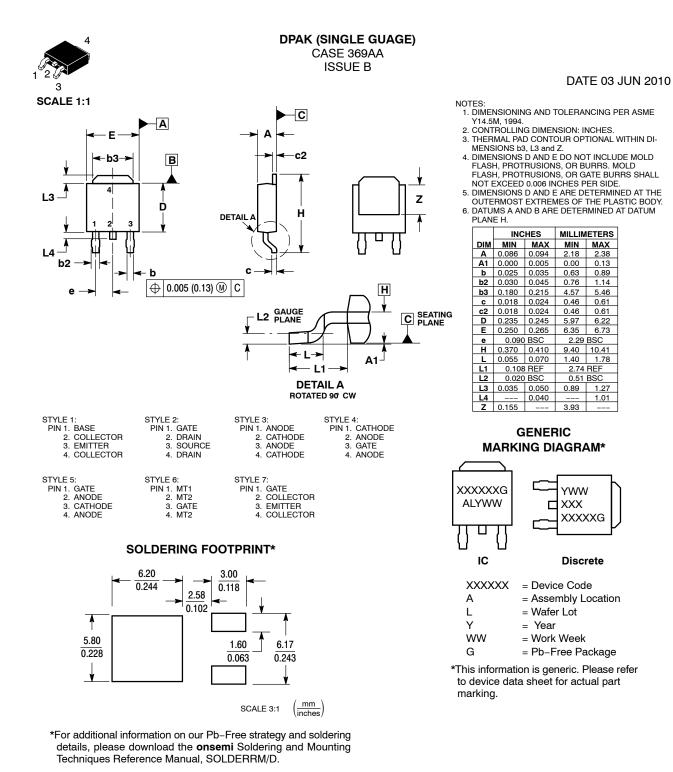
DPAK INSERTION MOUNT CASE 369 ISSUE O DATE 02 JAN 2000 SCALE 1:1 С $B \rightarrow$ NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. Е R MILLIMETERS INCHES л DIM MIN MAX MIN MAX A 0.235 0.250 B 0.250 0.265 5.97 6.35 Δ 6.35 6.73 C 0.086 0.094 D 0.027 0.035 2.19 0.69 2.38 2 3 0.88 S E 0.033 0.040 F 0.037 0.047 0.84 1.01 0.94 -T-1.19 G 0.090 BSC 2.29 BSC SEATING H 0.034 0.040 J 0.018 0.023 0.87 1.01 0.46 0.58 K 0.350 0.380 8.89 9.65 **R** 0.175 0.215 4.45 5.46 0.050 0.090 1.27 J S 2.28 F V 0.030 0.050 н 0.77 1.27 D 3 PL G 🔫 ⊕ 0.13 (0.005) M T

STYLE 1:		STYLE 2:		STYLE 3:		STYLE 4:		STYLE 5:		STYLE 6:	
PIN 1.	BASE	PIN 1.	GATE	PIN 1.	ANODE	PIN 1.	CATHODE	PIN 1.	GATE	PIN 1.	MT1
2.	COLLECTOR	2.	DRAIN	2.	CATHODE	2.	ANODE	2.	ANODE	2.	MT2
3.	EMITTER	3.	SOURCE	3.	ANODE	3.	GATE	3.	CATHODE	3.	GATE
4.	COLLECTOR	4.	DRAIN	4.	CATHODE	4.	ANODE	4.	ANODE	4.	MT2

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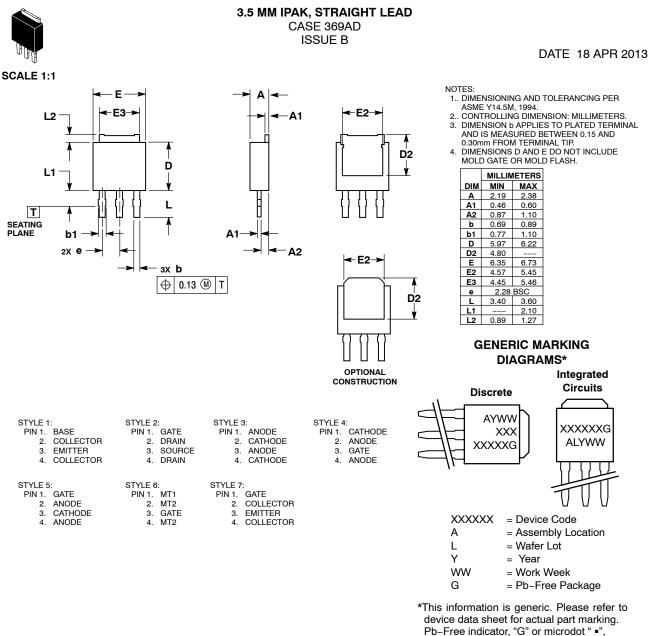


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